

TOSHIBA Field Effect Transistor Silicon P Channel MOS Type (U-MOS IV)

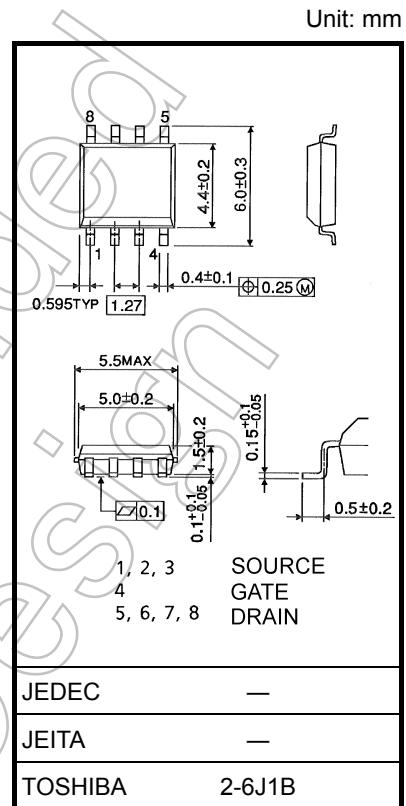
# TPC8115

Lithium Ion Battery Applications

Notebook PC Applications

Portable Equipment Applications

- Small footprint due to small and thin package
- Low drain-source ON resistance:  $R_{DS(ON)} = 6.5 \text{ m}\Omega$  (typ.)
- High forward transfer admittance:  $|Y_{fs}| = 40 \text{ S}$  (typ.)
- Low leakage current:  $I_{DSS} = -10 \mu\text{A}$  (max) ( $V_{DS} = -20 \text{ V}$ )
- Enhancement mode:  $V_{th} = -0.5$  to  $-1.2 \text{ V}$  ( $V_{DS} = -10 \text{ V}$ ,  $I_D = -1 \text{ mA}$ )



Weight: 0.080 g (typ.)

## Absolute Maximum Ratings ( $T_a = 25^\circ\text{C}$ )

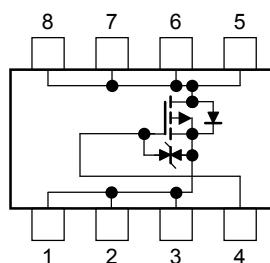
| Characteristics   | Symbol         | Rating     | Unit             |
|---|----------------|------------|------------------|
| Drain-source voltage  | $V_{DSS}$      | -20        | V                |
| Drain-gate voltage ( $R_{GS} = 20 \text{ k}\Omega$ )        | $V_{DGR}$      | -20        | V                |
| Gate-source voltage   | $V_{GSS}$      | $\pm 8$    | V                |
| Drain current   | DC (Note 1)    | $I_D$      | A                |
|   | Pulse (Note 1) | $I_{DP}$   |                  |
| Drain power dissipation ( $t = 10 \text{ s}$ )<br>(Note 2a) | $P_D$          | 1.9        | W                |
| Drain power dissipation ( $t = 10 \text{ s}$ )<br>(Note 2b) | $P_D$          | 1.0        | W                |
| Single pulse avalanche energy<br>(Note 3)                   | $E_{AS}$       | 26         | mJ               |
| Avalanche current   | $I_{AR}$       | -10        | A                |
| Repetitive avalanche energy<br>(Note 2a) (Note 4)           | $E_{AR}$       | 0.19       | mJ               |
| Channel temperature   | $T_{ch}$       | 150        | $^\circ\text{C}$ |
| Storage temperature range                                   | $T_{stg}$      | -55 to 150 | $^\circ\text{C}$ |

Note: (Note 1), (Note 2), (Note 3) and (Note 4): See the next page.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Please handle with caution.

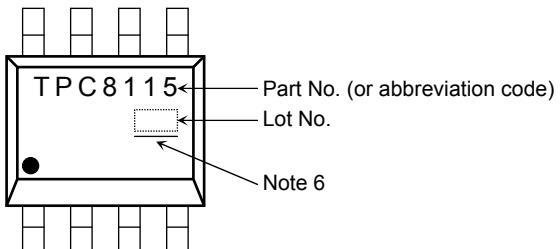
## Circuit Configuration



## Thermal Characteristics

| Characteristics   | Symbol          | Max  | Unit |
|---|-----------------|------|------|
| Thermal resistance, channel to ambient<br>( $t = 10$ s) | $R_{th}$ (ch-a) | 65.8 | °C/W |
| Thermal resistance, channel to ambient<br>( $t = 10$ s) | $R_{th}$ (ch-a) | 125  | °C/W |

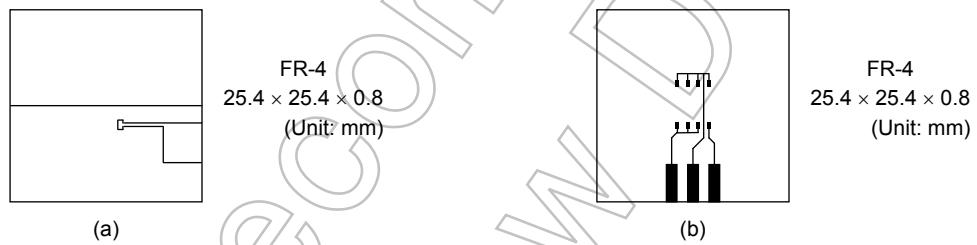
## Marking (Note 5)



Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2:

(a) Device mounted on a glass-epoxy board (a) (b) Device mounted on a glass-epoxy board (b)

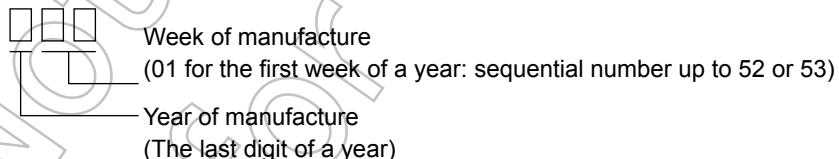


Note 3:  $V_{DD} = -16$  V,  $T_{ch} = 25^\circ\text{C}$  (initial),  $L = 0.2$  mH,  $R_G = 25\ \Omega$ ,  $I_{AR} = -10$  A

Note 4: Repetitive rating; pulse width limited by maximum channel temperature

Note 5: • on lower left of the marking indicates Pin 1.

※ Weekly code: (Three digits)



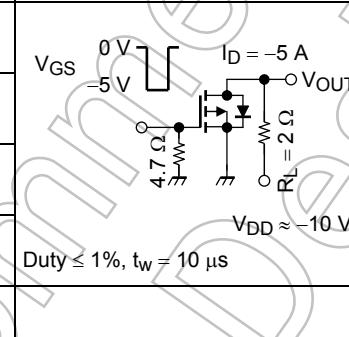
Note 6: A line under a Lot No. identifies the indication of product Labels.

Not underlined: [[Pb]]/INCLUDES > MCV

Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

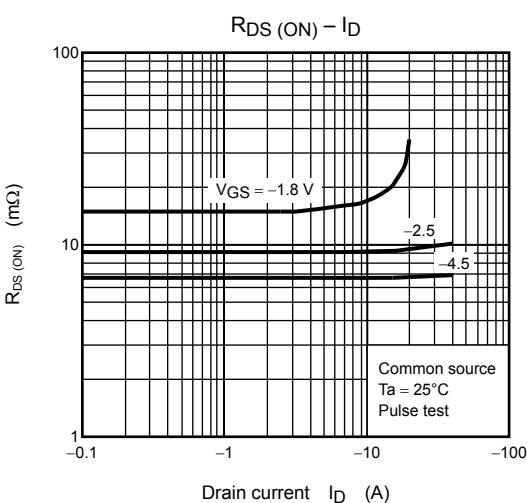
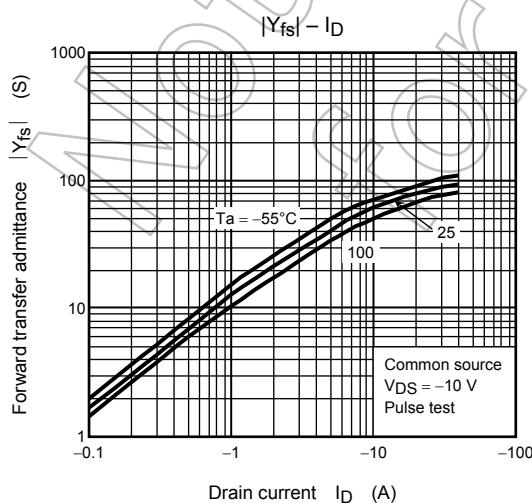
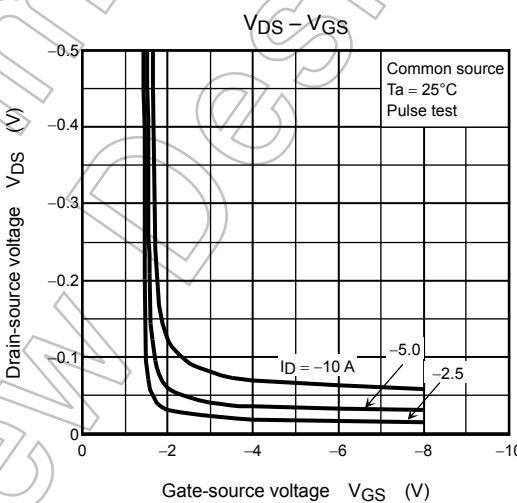
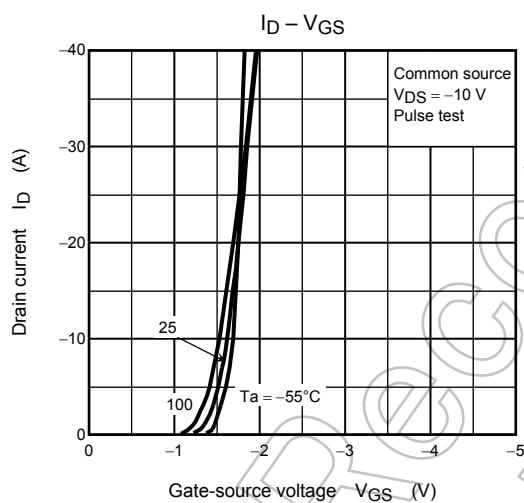
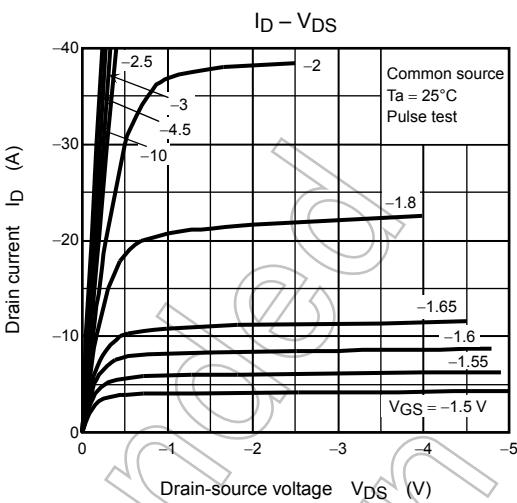
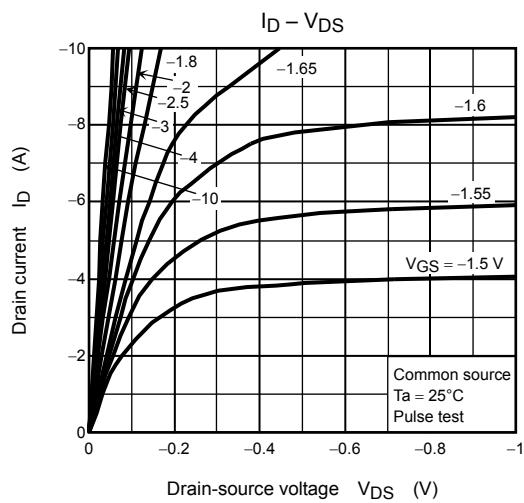
Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

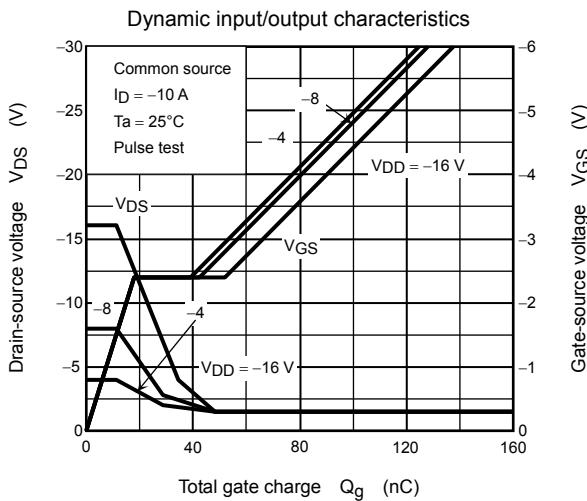
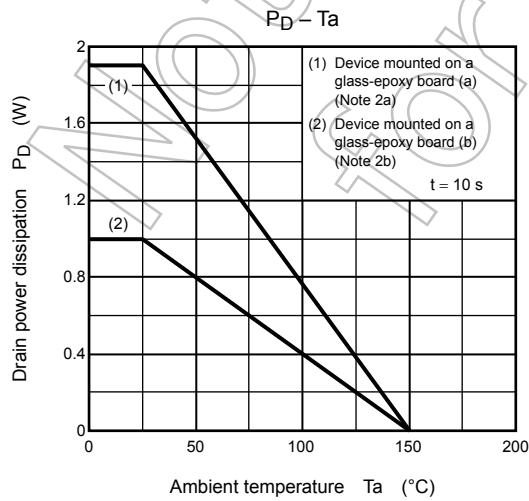
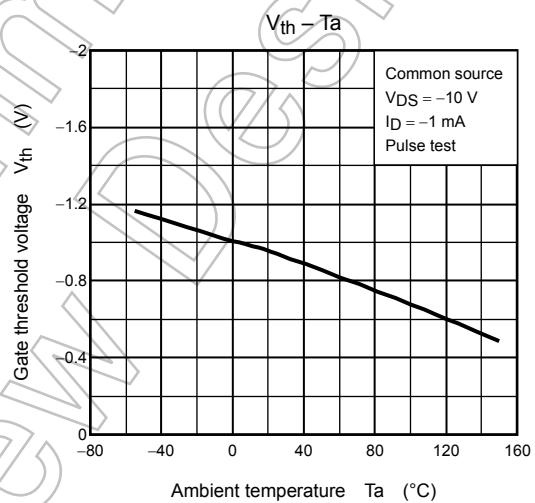
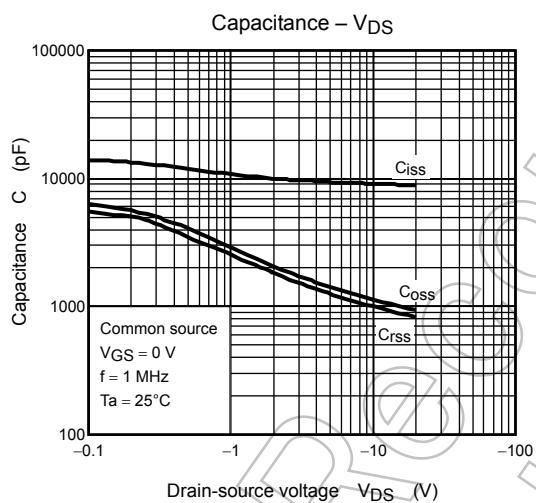
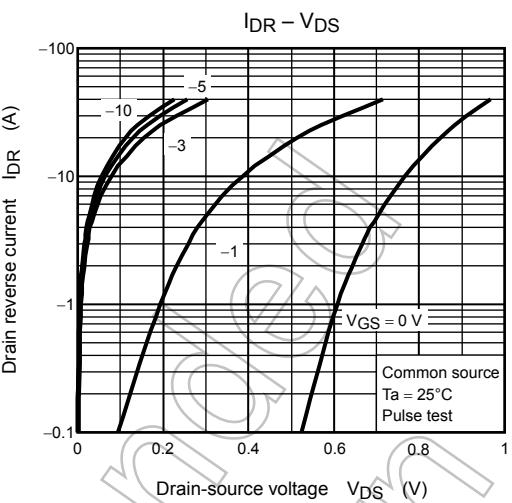
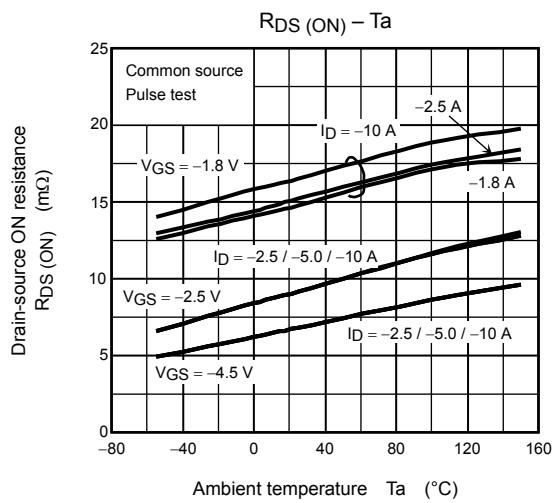
Electrical Characteristics ( $T_a = 25^\circ\text{C}$ )

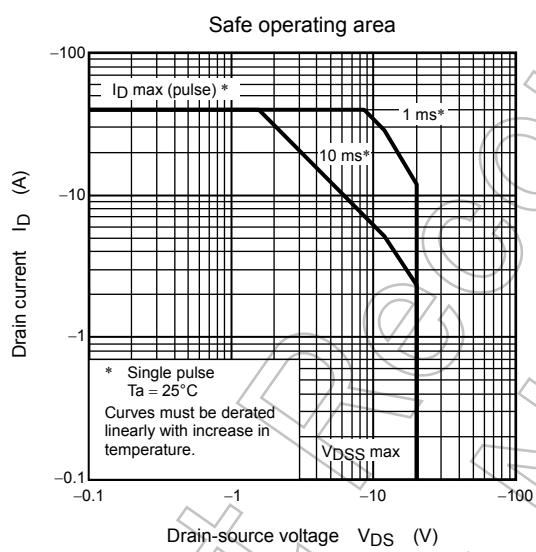
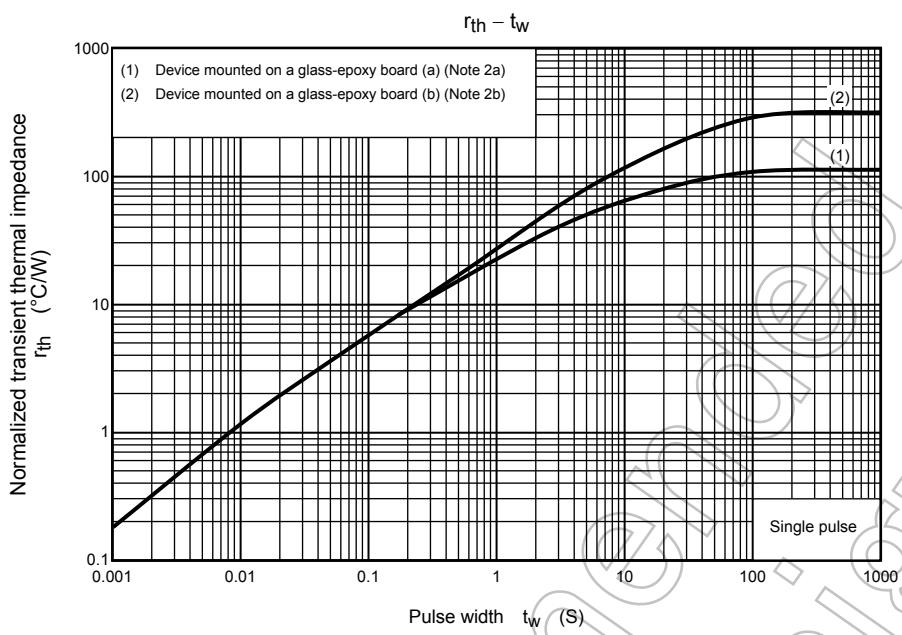
| Characteristics                                 | Symbol                      | Test Condition   | Min   | Typ. | Max      | Unit             |
|---|-----------------------------|--|---|------|----------|------------------|
| Gate leakage current                            | $I_{GSS}$                   | $V_{GS} = \pm 8 \text{ V}, V_{DS} = 0 \text{ V}$                           | —   | —    | $\pm 10$ | $\mu\text{A}$    |
| Drain cut-OFF current                           | $I_{DSS}$                   | $V_{DS} = -20 \text{ V}, V_{GS} = 0 \text{ V}$                             | —   | —    | -10      | $\mu\text{A}$    |
| Drain-source breakdown voltage                  | $V_{(\text{BR})\text{DSS}}$ | $I_D = -10 \text{ mA}, V_{GS} = 0 \text{ V}$                               | -20   | —    | —        | V                |
|   | $V_{(\text{BR})\text{DSX}}$ | $I_D = -10 \text{ mA}, V_{GS} = 8 \text{ V}$                               | -10   | —    | —        |                  |
| Gate threshold voltage                          | $V_{th}$                    | $V_{DS} = -10 \text{ V}, I_D = -1 \text{ mA}$                              | -0.5  | —    | -1.2     | V                |
| Drain-source ON resistance                      | $R_{DS(\text{ON})}$         | $V_{GS} = -1.8 \text{ V}, I_D = -5.0 \text{ A}$                            | —   | 15   | 30       | $\text{m}\Omega$ |
|   |                             | $V_{GS} = -2.5 \text{ V}, I_D = -5.0 \text{ A}$                            | —   | 9.0  | 14       |                  |
|   |                             | $V_{GS} = -4.5 \text{ V}, I_D = -5.0 \text{ A}$                            | —   | 6.5  | 10       |                  |
| Forward transfer admittance                     | $ Y_{fs} $                  | $V_{DS} = -10 \text{ V}, I_D = -5.0 \text{ A}$                             | 20  | 40   | —        | S                |
| Input capacitance                               | $C_{iss}$                   | $V_{DS} = -10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$          | —   | 9130 | —        | pF               |
| Reverse transfer capacitance                    | $C_{rss}$                   |  | —   | 1020 | —        |                  |
| Output capacitance                              | $C_{oss}$                   |  | —   | 1110 | —        |                  |
| Switching time                                  | Rise time                   | $t_r$  |  | —    | 14       | ns               |
|   | Turn-ON time                | $t_{on}$   |   | —    | 26       |                  |
|   | Fall time                   | $t_f$  |   | —    | 228      |                  |
|   | Turn-OFF time               | $t_{off}$  |   | —    | 666      |                  |
| Total gate charge (gate-source plus gate-drain) | $Q_g$                       | $V_{DD} \approx -16 \text{ V}, V_{GS} = -5 \text{ V}, I_D = -10 \text{ A}$ | —   | 115  | —        | nC               |
| Gate-source charge 1                            | $Q_{gs1}$                   |  | —   | 18   | —        |                  |
| Gate-drain ("miller") charge                    | $Q_{gd}$                    |  | —   | 34   | —        |                  |

Source-Drain Ratings and Characteristics ( $T_a = 25^\circ\text{C}$ )

| Characteristics                         | Symbol    | Test Condition                                 | Min | Typ. | Max | Unit |
|---|-----------|--|-----|------|-----|------|
| Drain reverse current<br>Pulse (Note 1) | $I_{DRP}$ | —  | —   | —    | -40 | A    |
| Forward voltage (diode)                 | $V_{DSF}$ | $I_{DR} = -10 \text{ A}, V_{GS} = 0 \text{ V}$ | —   | —    | 1.2 | V    |







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